**PNP/NPN Epitaxial Planar Silicon Transistors** 



2SB1397/2SD2100

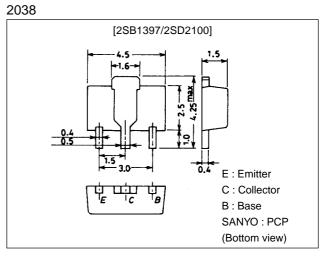
# **Compact Motor Driver Applications**

## **Features**

- $\cdot$  Low saturation voltage.
- $\cdot$  Contains diode between collector and emitter.
- $\cdot$  Contains bias resistance between base and emitter.
- · Large current capacity.
- Small-sized package making it easy to provide highdensity, small-sized hybrid ICs.

# Package Dimensions

unit:mm



():2SB1397

# **Specifications**

#### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		(–)25	V
Collector-to-Emitter Voltage	VCEO		(-)20	V
Emitter-to-Base Voltage	VEBO		(–)6	V
Collector Current	۱ <sub>C</sub>		(-)2	A
Collector Current (Pulse)	I <sub>CP</sub>		(-)4	A
Collector Dissipation	PC	Mounted on ceramic board (250mm <sup>2</sup> ×0.8mm)	1.3	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

### Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =(-)20V, I <sub>E</sub> =0			(–)1.0	μA
DC Current Gain	h <sub>FE</sub> 1	V <sub>CE</sub> =(-)2V, I <sub>C</sub> =(-)0.5A	(–)70			
	h <sub>FE</sub> 2	V <sub>CE</sub> =(-)2V, I <sub>C</sub> =(-)2A	(–)50			
Gain-Bandwidth Product	fT	V <sub>CE</sub> =(-)2V, I <sub>C</sub> =(-)0.5A		(300)		MHz
				200		MHz
Output Capacitance	Cob	V <sub>CB</sub> =(-)10V, f=1MHz		(40)25		pF

Marking: 2SB1397: BP

2SD2100 : DP

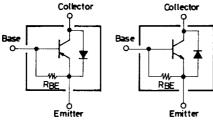
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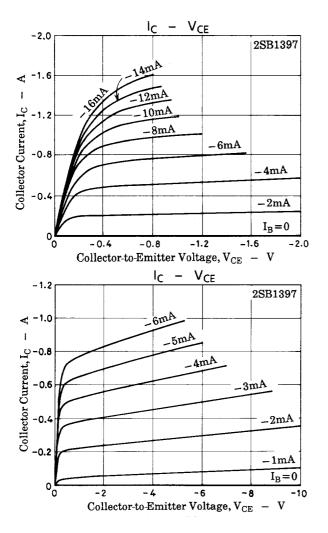
Parameter	Symbol	Conditions	Ratings			Unit
	Symbol		min	typ	max	Unit
Collector-to-Emitter Saturation Voltage	VCE(sat)	I <sub>C</sub> =(-)1A, I <sub>B</sub> =(-)50mA		(–)0.25	(–)0.5	V
Base-to-Emitter Saturation Voltage	VBE(sat)	I <sub>C</sub> =(-)1A, I <sub>B</sub> =(-)50mA			(–)1.5	V
Collector-to-Base Breakdown Voltage	V <sub>(BR)</sub> CBO	I <sub>C</sub> =(-)10μA, I <sub>E</sub> =0	(–)25			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO1	I <sub>C</sub> =(−)10µA, R <sub>BE</sub> =∞	(–)25			V
	V(BR)CEO2	I <sub>C</sub> =(−)10mA, R <sub>BE</sub> =∞	(–)20			V
Diode Forwad Voltage	VF	I <sub>F</sub> =0.5A			(–)1.5	k\$Ø2
Base-to-Emitter Resistance	R <sub>BE</sub>			1.6		

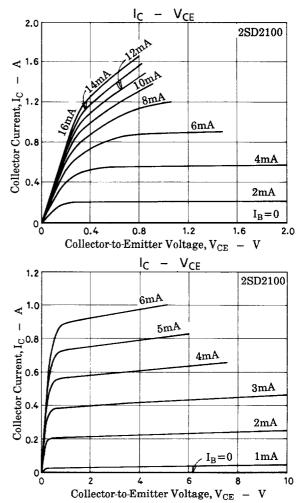
## **Electrical Connection**



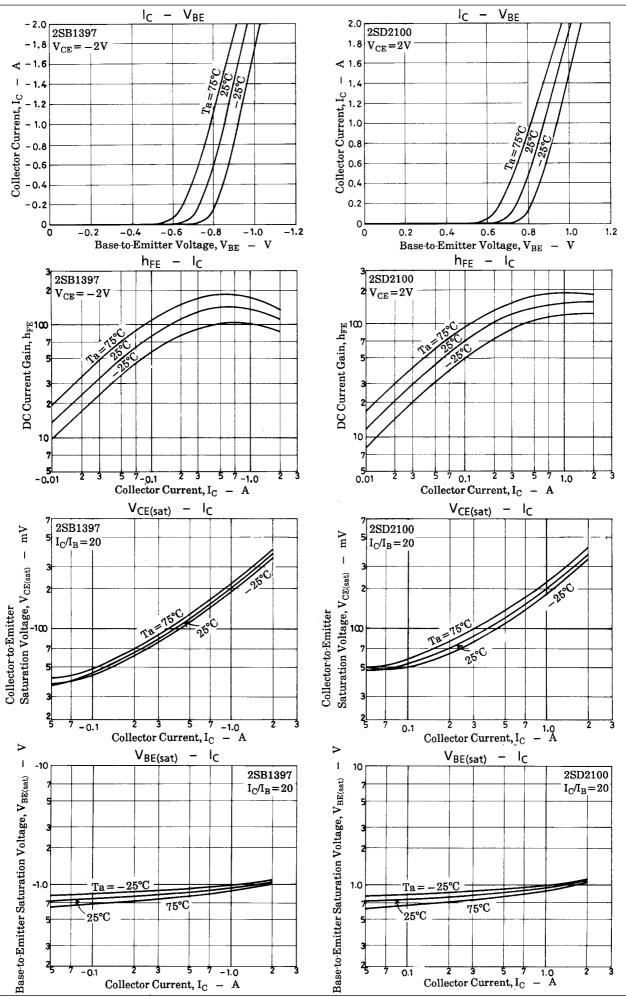
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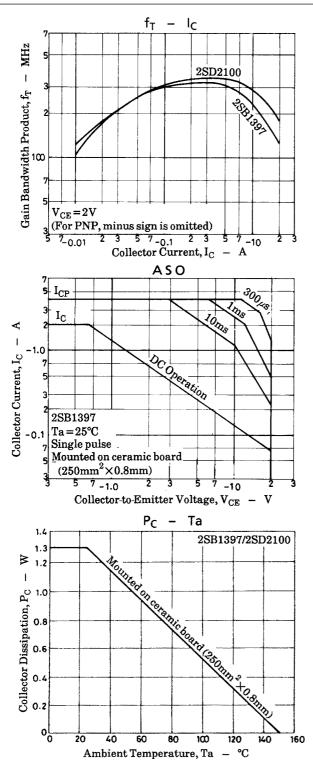


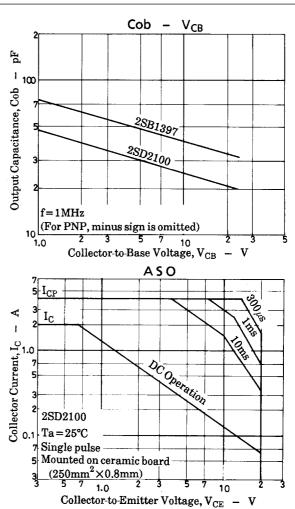


## 2SB1397/2SD2100



No.3176-3/5





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